

Application Data Sheet

Application Information

Application number::	Not Yet Assigned
Application Type::	Utility
Subject Matter::	Utility
Suggested Group Art Unit::	N/A
CD-ROM or CD-R?::	No
Sequence submission?::	No
Computer Readable Form (CRF)?::	No
Title::	Method of Forming a Barrier Metal in a Semiconductor Device
Attorney Docket Number::	29936/39479
Request for Early Publication?::	No
Request for Non-Publication?::	No
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

Applicant Information

Applicant Authority Type::	Inventor
Primary Citizenship Country::	
Status::	
Given Name::	Chang Jin
Family Name::	KO
City of Residence::	
Country of Residence::	Republic of Korea
Street of mailing address::	San 136-1, Ami-Ri, Bubal-Uep, Ichon-Shi, Kyungki-Do
City of mailing address::	
Country of mailing address::	Republic of Korea
Postal or Zip Code of mailing address::	

Correspondence Information

Correspondence Customer Number:: 04743
Phone number:: (312) 474-6300
Fax number:: (312) 474-0448

Representative Information

Representative Customer Number:: 04743

Domestic Priority Information

Application:: Continuity Type:: Parent Application:: Parent Filing Date::
This Application

Foreign Priority Information

Country::	Application number::	FilingDate::	Priority Claimed::
Republic of Korea	10-2002-0084338	December 26, 2002	

Assignee Information

Assignee name:: Hynix Semiconductor Inc., of San 136-1,
Ami-Ri, Bubal-Uep, Ichon-Shi, Kyungki-Do,
Republic of Korea